ΡΛΝ	JIT
	SEMI
	CONDUCTOR

### 20V P-Channel Enhancement Mode MOSFET

Current

-3.4 A

#### Features

Voltage

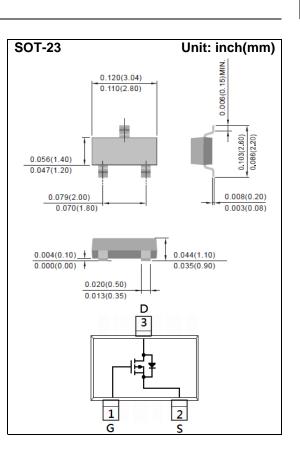
• RDS(ON) , VGS@-4.5V, ID@-3.4A<82mΩ

-20 V

- RDS(ON) , VGS@-2.5V, ID@-2.2A<110mΩ
- RDS(ON) , VGS@-1.8V, ID@-1.2A<146mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

#### **Mechanical Data**

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams
- Marking: A13



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	-20	V
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 12	V
Continuous Drain Current		lo	-3.4	А
Pulsed Drain Current		I <sub>DM</sub>	-13.6	А
Power Dissipation	T₂=25°C		1.25	W
	Derate above 25°C	PD	10	mW/°C
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~150	٥C
Typical Thermal resistance - Junction to Ambient <sup>(Note 3)</sup>		Reja	100	°C/W



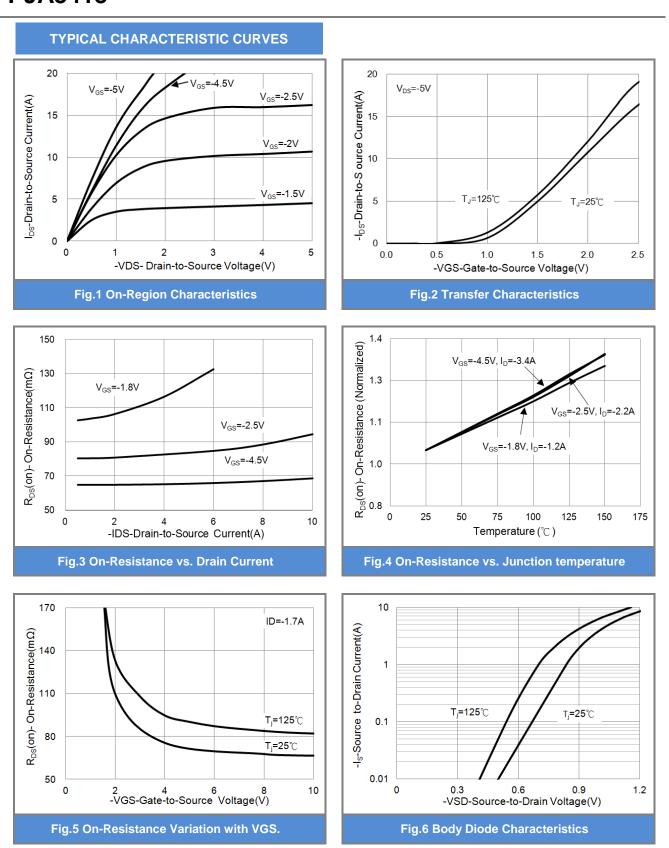
#### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static		·					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-20	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-0.4	-0.65	-1.2	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-3.4A	-	65	82	mΩ	
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-2.2A	-	82	110		
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-1.2A	-	103	146		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =-20V, $V_{GS}$ =0V	-	0.01	-1	uA	
Gate-Source Leakage Current	lgss	V <sub>GS</sub> = <u>+</u> 12V, V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA	
Dynamic							
Total Gate Charge	Qg	V <sub>DS</sub> =-10V, I <sub>D</sub> =-3.4A,	-	7	-	nC	
Gate-Source Charge	$Q_{gs}$		-	1	-		
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =-4.5V (Note 1,2)	-	1.8	-		
Input Capacitance	Ciss		-	522	-		
Output Capacitance	Coss	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V,	-	55	-	pF	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	40	-		
Switching							
Turn-On Delay Time	td <sub>(on)</sub>		-	10	-		
Turn-On Rise Time	tr	V <sub>DD</sub> =-10V, I <sub>D</sub> =-3.4A,		4	-		
Turn-Off Delay Time	td <sub>(off)</sub>	V <sub>GS</sub> =-4.5V, R <sub>G</sub> =6Ω <sup>(Note 1,2)</sup>	-	34	-	ns	
Turn-Off Fall Time	tf	KG=012 (1000 1)2)		5			
Drain-Source Diode		·					
Maximum Continuous Drain-Source Diode Forward Current	ls		-	-	-1.5	A	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-1.0A, V <sub>GS</sub> =0V	-	0.77	-1.2	V	

NOTES :

- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R<sub>0JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited







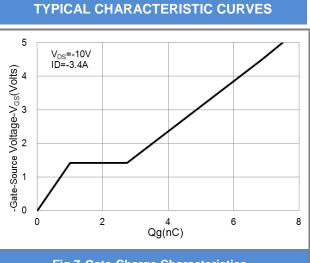


Fig.7 Gate-Charge Characteristics

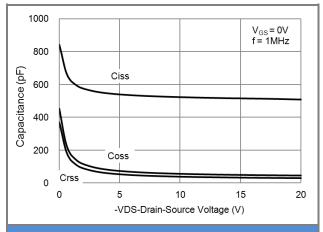


Fig.9 Threshold Voltage Variation with Temperature.

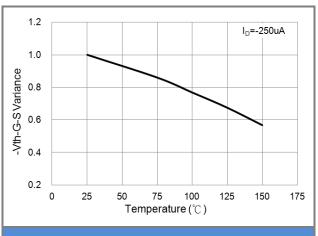


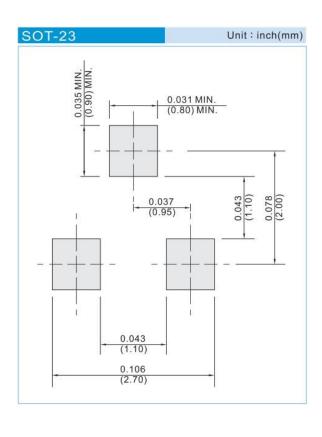
Fig.8 Threshold Voltage Variation with Temperature.



### **Product and Packing Information**

Part No.	Package Type Packing Type		Marking
PJA3413	SOT-23	3K pcs / 7" reel	A13

#### **Mounting Pad Layout**





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